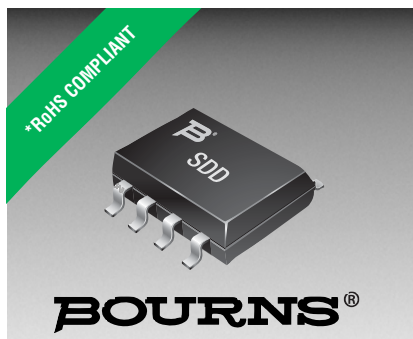




Features

- RoHS compliant*
- Protects four lines
- Unidirectional and bidirectional configurations
- ESD protection: 30 kV max.

Applications

- Audio/video inputs
- RS-232, RS-422 and RS-423 data lines
- Portable electronics
- Medical sensors

CDNBS08-T03~T36C - TVS Diode Array Series

General Information

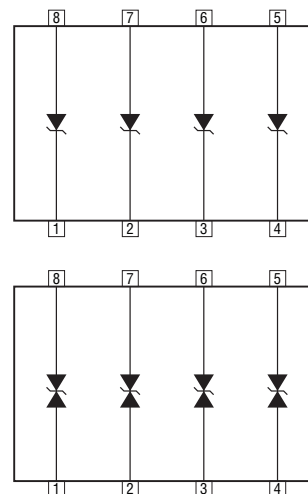
The markets of portable communications, computing and video equipment are challenging the semiconductor industry to develop increasingly smaller electronic components.

Bourns offers Steering Diode/Transient Voltage Suppressor Array diodes for surge and ESD protection applications in an eight lead narrow body SOIC package size format. The Transient Voltage Suppressor Array series offer a choice of voltage types ranging from 3 V to 36 V in unidirectional and bidirectional configurations. Bourns® Chip Diodes conform to JEDEC standards, are easy to handle on standard pick and place equipment and their flat configuration minimizes roll away.

The Bourns® device will meet IEC 61000-4-2 (ESD), IEC 61000-4-4 (EFT) and IEC 61000-4-5 (Surge) requirements.

Thermal Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Parameter	Symbol	Max.	Unit
Operating Temperature	T _J	-55 to +150	°C
Storage Temperature	T _{STG}	-55 to +150	°C



Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Parameter	Symbol	CDNBS08-														Unit
		Uni-T03	Bi-T03C	Uni-T05	Bi-T05C	Uni-T08	Bi-T08C	Uni-T12	Bi-T12C	Uni-T15	Bi-T15C	Uni-T24	Bi-T24C	Uni-T36	Bi-T36C	
Min. Breakdown Voltage @ 1 mA	V _{BR}	3.3		6.0		8.5		13.3		16.7		26.7		40.0		V
Working Peak Voltage	V _{WM}	3.0		5.0		8.0		12.0		15.0		24.0		36.0		V
Max. Clamping Voltage V _C @ I _P = 1 A ¹	V _C	8.0		9.8		13.4		19.0		24.0		43.0		51.0		V
Typ. Clamping Voltage @ 8/20 μs V _C @ I _{PP} ¹	V _C	10.9 V @ 43 A		13.5 V @ 42 A		16.9 V @ 34 A		25.9 V @ 21 A		30.0 V @ 17 A		49.0 V @ 12 A		76.8 V @ 9 A		V
Max. Leakage Current @ V _{WM}	I _D	125		20		10		1		1		1		1		μA
Max. Cap. Bidirectional @ 0 V, 1 MHz	C _{J(SD)}	450		308		300		105		80		50		45		pF
ESD Protection per IEC 61000-4-2 Contact - Min. Contact - Max. Air - Min. Air - Max.	ESD	±8 ±30 ±15 ±30														kV
Peak Pulse Power (t _p = 8/20 μs) ²	P _{PP}	500														W
Forward Voltage @ 100 mA, 300 μs - Square Wave ³	V _F	1.5														V

Notes:

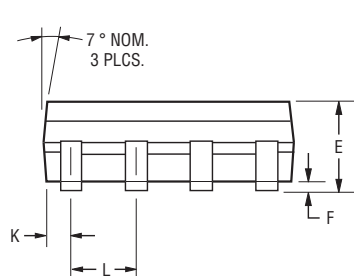
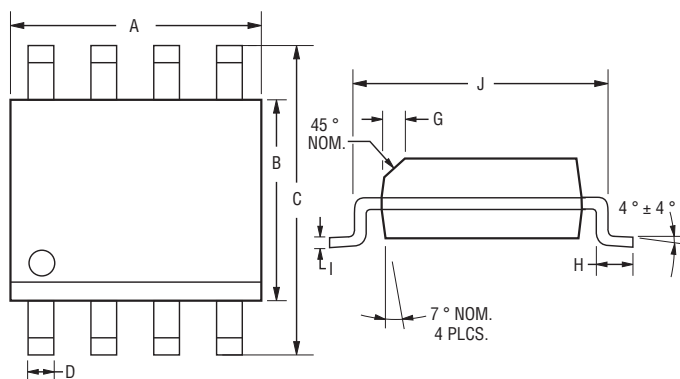
1. See Pulse Wave Form.
2. See Peak Pulse Power vs. Pulse Time.
3. Only applies to unidirectional devices.
4. Part numbers with a "C" suffix are bidirectional devices, i.e. CDNBS08-T03C.

CDNBS08-T03~T36C - TVS Diode Array Series

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Product Dimensions

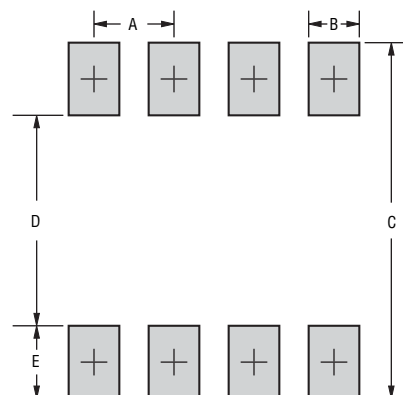
This is an RoHS compliant molded JEDEC narrow body SO-8 package with 100 % Sn plating on the lead frame. It weighs approximately 15 mg and has a flammability rating of UL 94V-0.



DIMENSIONS = $\frac{\text{MILLIMETERS}}{\text{(INCHES)}}$

Dimensions	
A	$\frac{4.80 - 5.00}{(0.189 - 0.197)}$
B	$\frac{3.81 - 4.00}{(0.150 - 0.157)}$
C	$\frac{5.80 - 6.20}{(0.228 \pm 0.244)}$
D	$\frac{0.36 - 0.51}{(0.014 - 0.020)}$
E	$\frac{1.35 - 1.75}{(0.053 - 0.069)}$
F	$\frac{0.102 - 0.203}{(0.004 - 0.008)}$
G	$\frac{0.25 - 0.50}{(0.010 - 0.020)}$
H	$\frac{0.51 - 1.12}{(0.020 - 0.044)}$
I	$\frac{0.190 - 0.229}{(0.0075 - 0.0090)}$
J	$\frac{4.60 - 5.21}{(0.181 - 0.205)}$
K	$\frac{0.28 - 0.79}{(0.011 - 0.031)}$
L	$\frac{1.27}{(0.050)}$

Recommended Footprint



Dimensions	
A	$\frac{1.143 - 1.397}{(0.045 - 0.065)}$
B	$\frac{0.635 - 0.889}{(0.025 - 0.035)}$
C	$\frac{6.223}{(0.245)} \text{ Min.}$
D	$\frac{3.937 - 4.191}{(0.155 - 0.165)}$
E	$\frac{1.016 - 1.27}{(0.040 - 0.050)}$

Typical Part Marking

CDNBS08-T03.....SDL	CDNBS08-T12C.....SDD
CDNBS08-T03C.....SDM	CDNBS08-T15.....SDE
CDNBS08-T05.....SDA	CDNBS08-T15C.....SDF
CDNBS08-T05C.....SDB	CDNBS08-T24.....SDG
CDNBS08-T08.....SDJ	CDNBS08-T24C.....SDH
CDNBS08-T08C.....SDK	CDNBS08-T36.....SDN
CDNBS08-T12.....SDC	CDNBS08-T36C.....SDP

How to Order

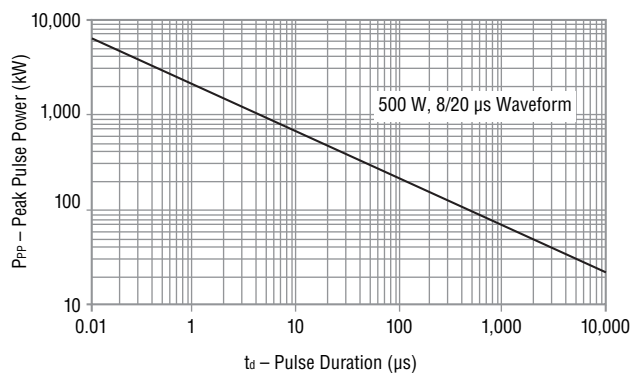
Common Code	CD NBS08 - T 03 C
Chip Diode	
Package	
NBS08 = Narrow Body SOIC8 Package	
Model	
T = Transient Voltage Suppressor	
Working Peak Voltage	
03 = 3 V _{RWM} (Volts)	
Suffix	
C = Bidirectional Diode	

Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

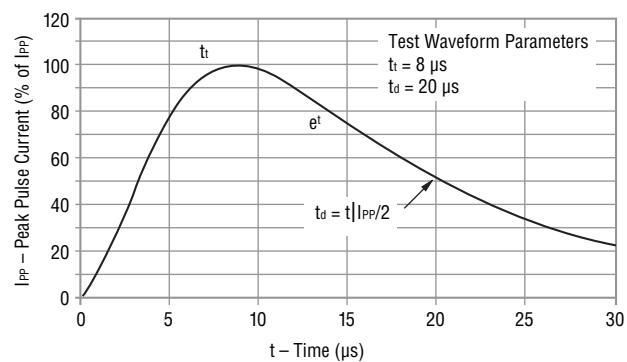
CDNBS08-T03~T36C - TVS Diode Array Series

Performance Graphs

Peak Pulse Power vs Pulse Time

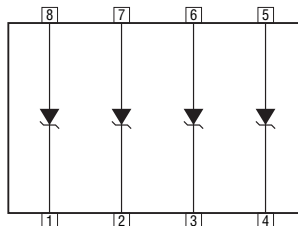


Pulse Waveform

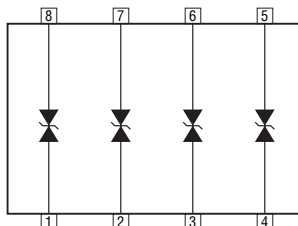


Block Diagram

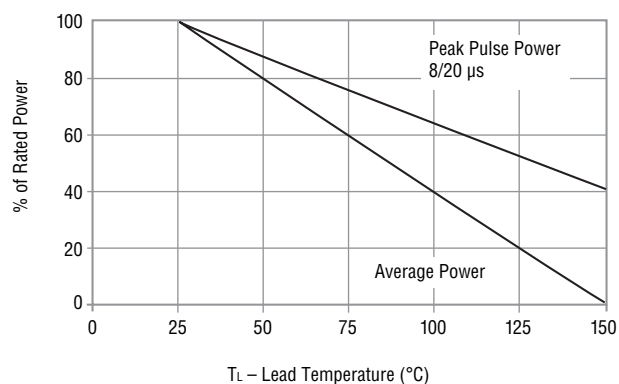
Unidirectional



Bidirectional



Power Derating Curve



Device Pinout

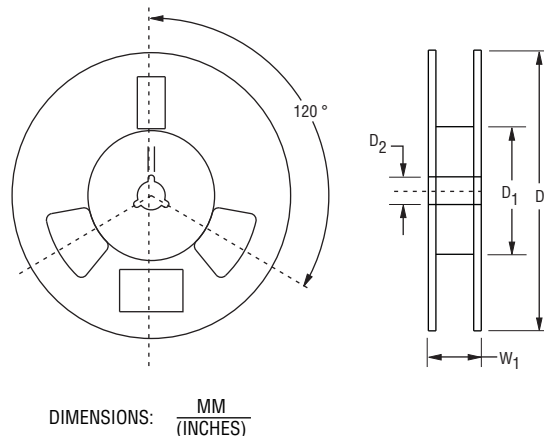
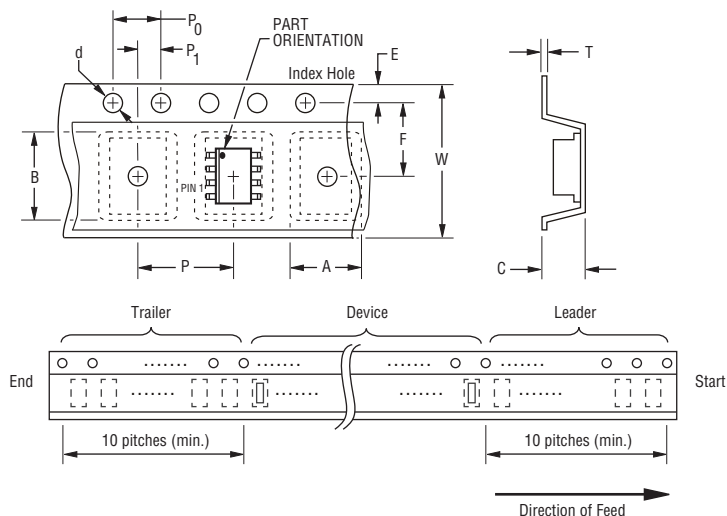
Pin	Function
1	I/O 1
2	I/O 2
3	I/O 3
4	I/O 4
5	GND
6	GND
7	GND
8	GND

CDNBS08-T03~T36C - TVS Diode Array Series

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Packaging Information

The product is packaged in tape and reel format per EIA-481 standard.



DIMENSIONS: $\frac{\text{MM}}{\text{(INCHES)}}$

Item	Symbol	NSOIC 8L
Carrier Width	A	$\frac{6.7 \pm 0.10}{(0.264 \pm 0.004)}$
Carrier Length	B	$\frac{5.5 \pm 0.10}{(0.217 \pm 0.004)}$
Carrier Depth	C	$\frac{2.10 \pm 0.10}{(0.083 \pm 0.004)}$
Sprocket Hole	d	$\frac{1.55 \pm 0.05}{(0.061 \pm 0.002)}$
Reel Outside Diameter	D	$\frac{330}{(12.992)}$
Reel Inner Diameter	D ₁	$\frac{80.0}{(3.1500)} \text{ MIN.}$
Feed Hole Diameter	D ₂	$\frac{13.0 \pm 0.20}{(0.512 \pm 0.008)}$
Sprocket Hole Position	E	$\frac{1.75 \pm 0.10}{(0.069 \pm 0.004)}$
Punch Hole Position	F	$\frac{3.50 \pm 0.05}{(0.138 \pm 0.002)}$
Punch Hole Pitch	P	$\frac{8.00 \pm 0.10}{(0.315 \pm 0.004)}$
Sprocket Hole Pitch	P ₀	$\frac{4.00 \pm 0.10}{(0.157 \pm 0.004)}$
Embossment Center	P ₁	$\frac{2.00 \pm 0.05}{(0.079 \pm 0.002)}$
Overall Tape Thickness	T	$\frac{0.20 \pm 0.10}{(0.008 \pm 0.004)}$
Tape Width	W	$\frac{12.00 \pm 0.20}{(0.472 \pm 0.008)}$
Reel Width	W ₁	$\frac{18.4}{(0.724)} \text{ MAX.}$
Quantity per Reel	--	2500

BOURNS®

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Fax: +1-951 781-5700

www.bourns.com

REV. 12/12

Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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Факс: 8 (812) 320-02-42

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